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TriQSiC™ 2300V Silicon Carbide Power MOSFET G2

Features

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Benefits

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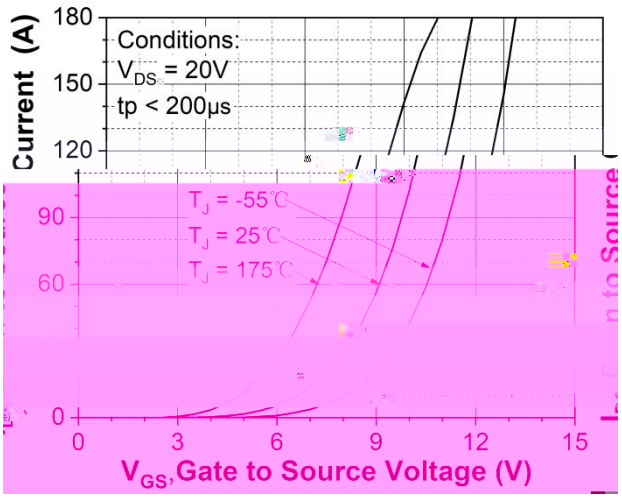
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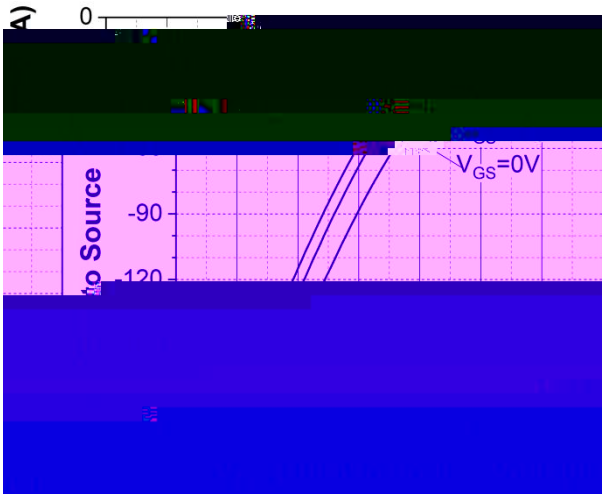
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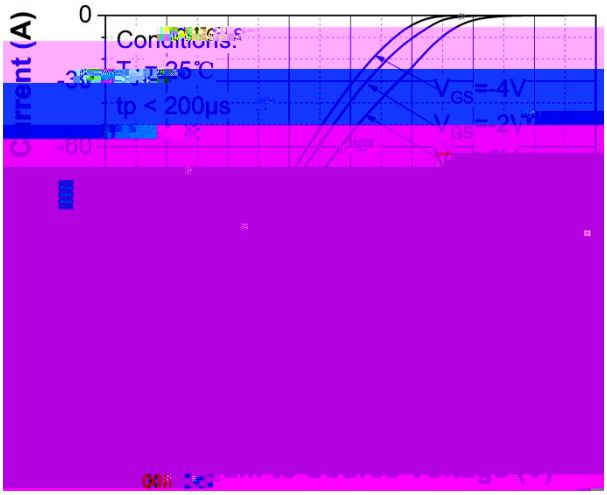
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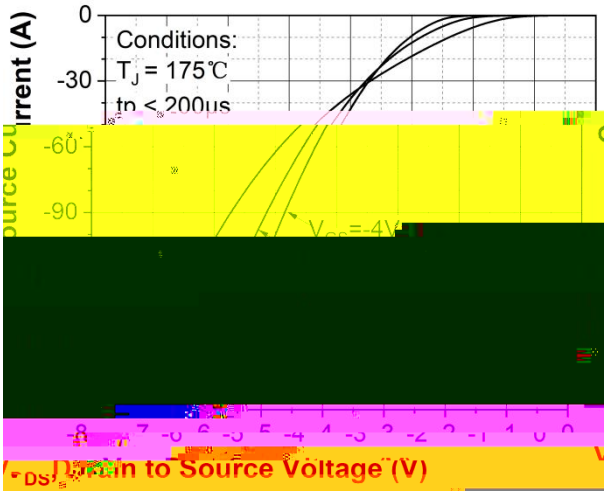
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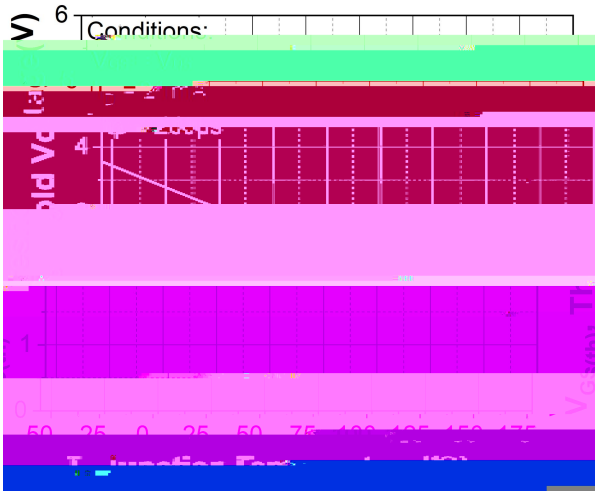
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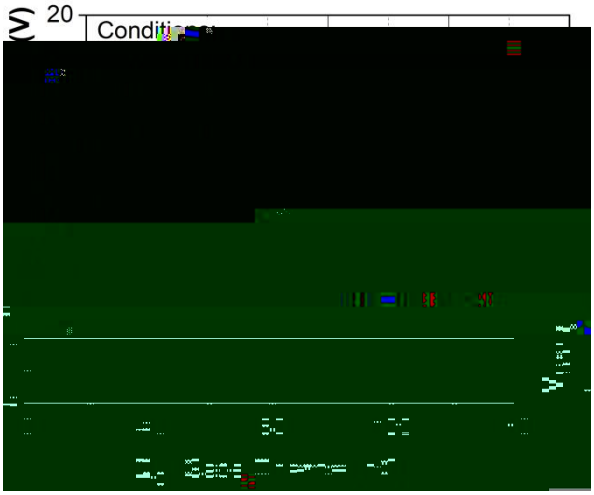




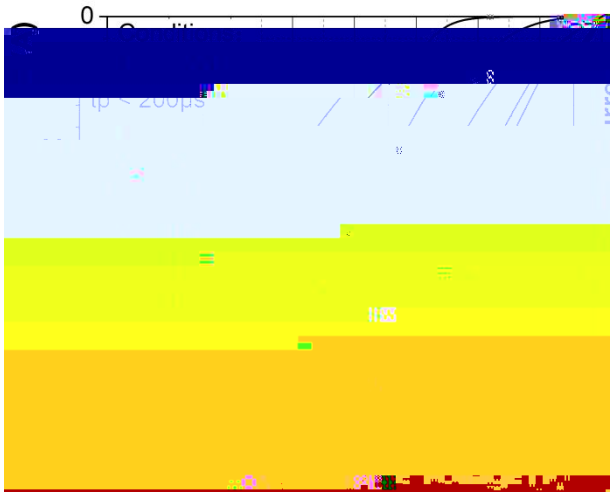


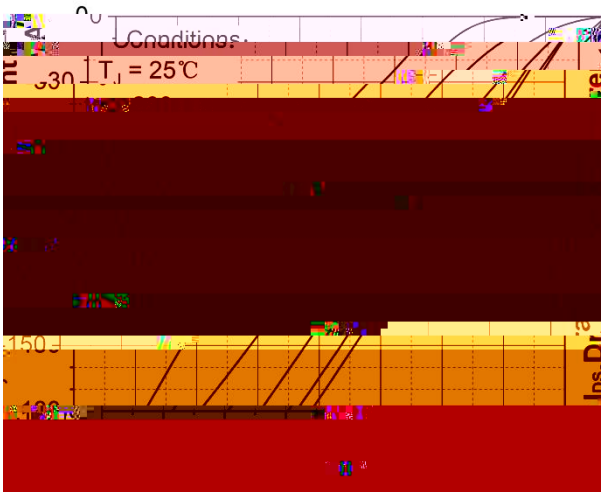


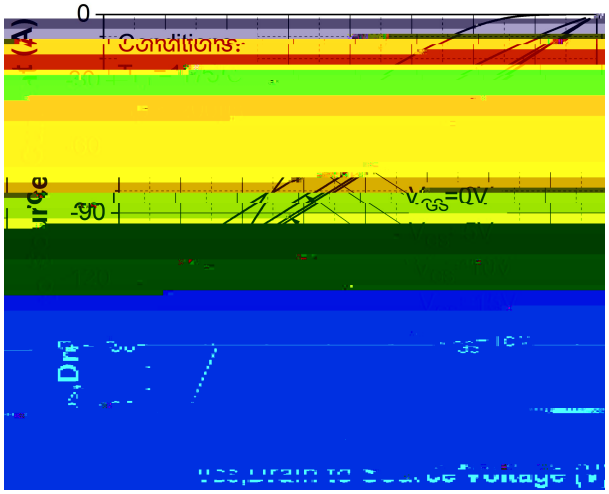


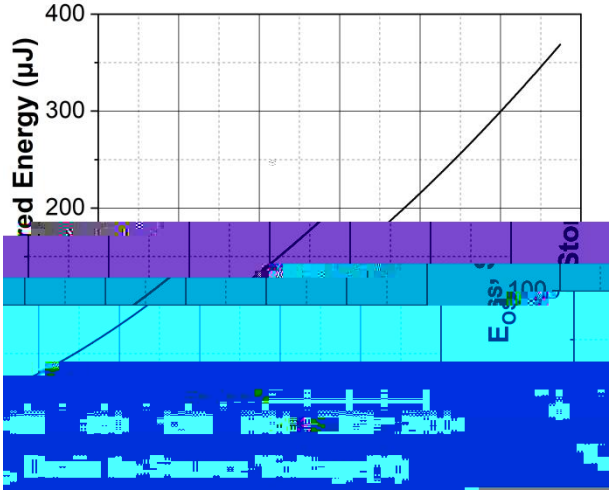


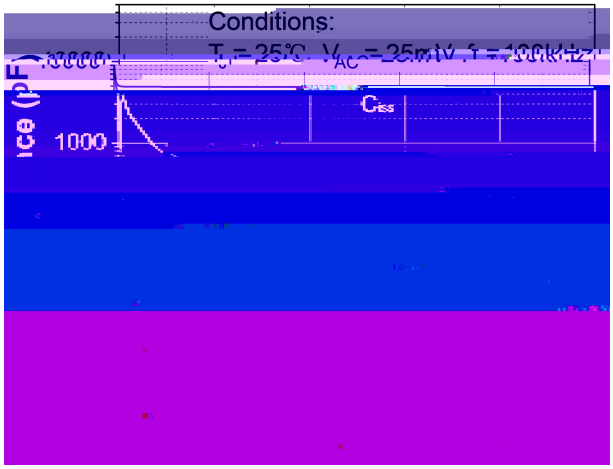
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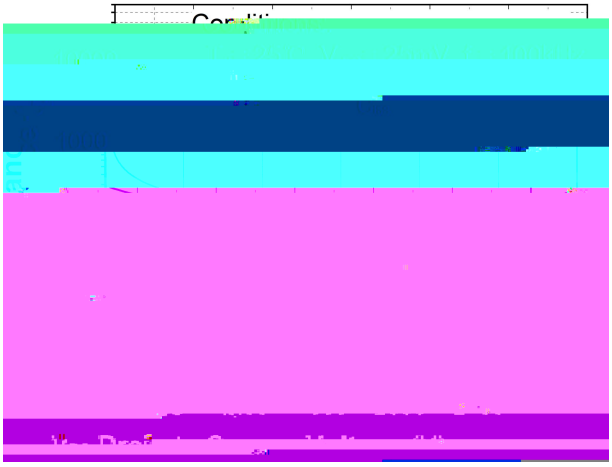












4 Mechanical parameters

4.1 Dimensions and metallization

Parameter	Typical value	Unit	Metallization

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Revision history

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